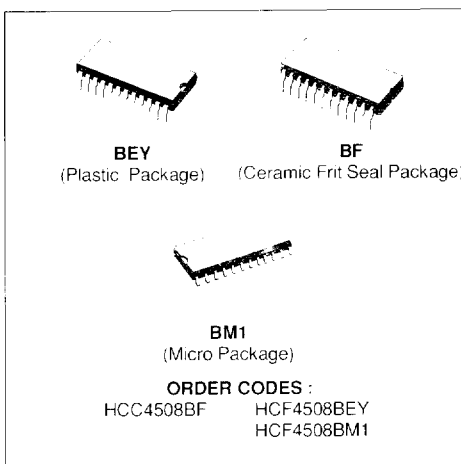


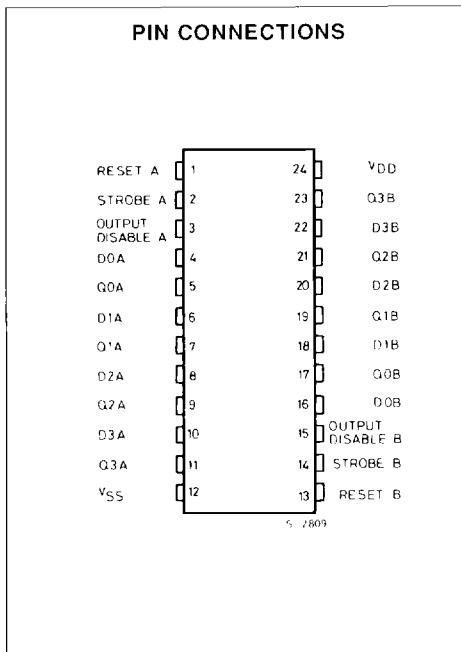
DUAL 4-BIT LATCH

- TWO INDEPENDENT 4-BIT LATCHES
- INDIVIDUAL MASTER RESET FOR EACH 4-BIT-LATCH
- 3-STATE OUTPUTS WITH HIGH-IMPEDANCE STATE FOR BUS LINE APPLICATION
- MEDIUM-SPEED OPERATION : $t_{PHL} = t_{PLH} = 70\text{ns}$ (TYP.) AT $V_{DD} = 10\text{V}$ AND $C_L = 50\text{pF}$
- QUIESCENT CURRENT SPECIFIED TO 20V FOR HCC DEVICE
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT CURRENT OF 100nA AT 18V AND 25 C FOR HCC DEVICE
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC TENTATIVE STANDARD N⁰. 13A. "STANDARD SPECIFICATIONS FOR DESCRIPTION OF "B" SERIES CMOS DEVICES"

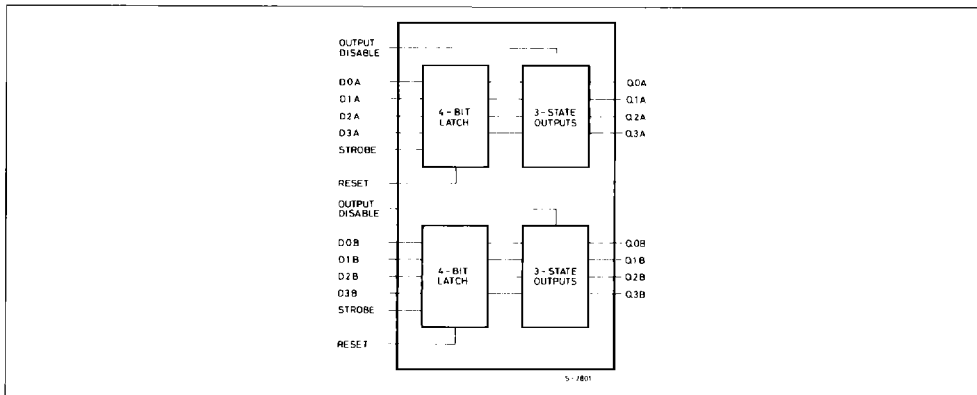


DESCRIPTION

The **HCC4508B** (extended temperature range) and the **HCF4508B** (intermediate temperature range) are monolithic integrated circuits available in 24-lead dual in-line plastic or ceramic package and plastic micro package. The **HCC/HCF4508B** dual 4-bit latch contains two identical 4-bit latches with separate STROBE, RESET, and OUTPUT DISABLE controls. With the STROBE line in the high state, the data on the "D" inputs appear at the corresponding "Q" outputs provided the DISABLE line is in the low state. Changing the STROBE line to the low state locks the data into the latch. A high on the reset line forces the outputs to a low level regardless of the state of the STROBE input. The outputs are forced to the high-impedance state for bus line applications by a high level on the DISABLE input.



FUNCTIONAL DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{DD}^*	Supply Voltage : HCC Types	- 0.5 to + 20	V
	HCF Types	- 0.5 to + 18	V
V_i	Input Voltage	- 0.5 to $V_{DD} + 0.5$	V
I_i	DC Input Current (any one input)	± 10	mA
P_{tot}	Total Power Dissipation (per package)	200	mW
	Dissipation per Output Transistor for T_{op} = Full Package-temperature Range	100	mW
T_{op}	Operating Temperature : HCC Types	- 55 to + 125	$^{\circ}\text{C}$
	HCF Types	- 40 to + 85	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	- 65 to + 150	$^{\circ}\text{C}$

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for external periods may affect device reliability.

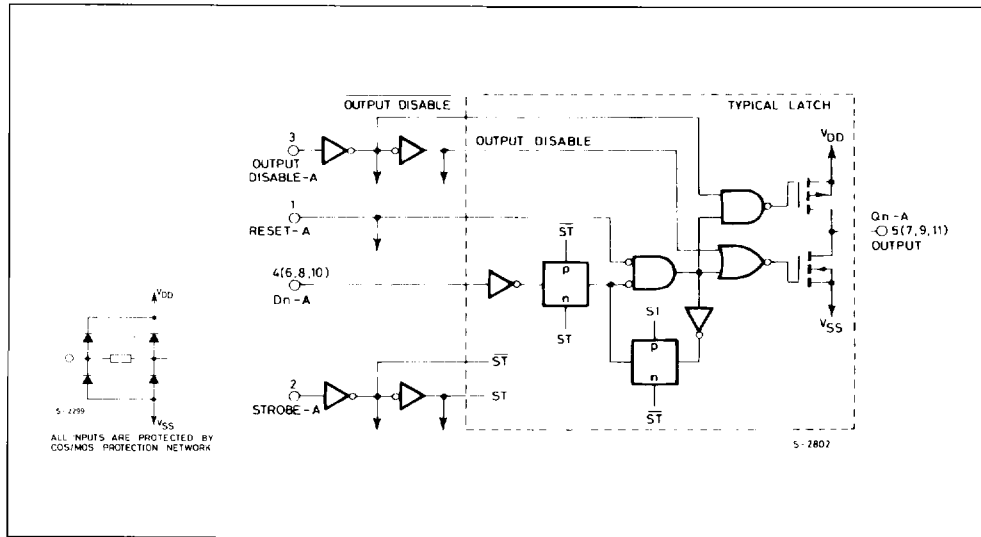
* All voltage values are referred to V_{SS} pin voltage.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage : HCC Types	3 to + 18	V
	HCF Types	3 to + 15	V
V_i	Input Voltage	0 to V_{DD}	V
T_{op}	Operating Temperature : HCC Types	- 55 to + 125	$^{\circ}\text{C}$
	HCF Types	- 40 to + 85	$^{\circ}\text{C}$

LOGIC DIAGRAM (A section)

1 OF 4 IDENTICAL LATCHES WITH COMMON OUTPUT DISABLE, RESET AND STROBE



TRUTH TABLE

Reset	Disab.	Strobe	D Input	Q Input
0	0	1	1	1
0	0	1	0	0
0	0	0	X	Latched
1	0	X	X	0
X	1	X	X	Z

1 = High level
0 = Low level

X = Don't care
Z = High impedance

STATIC ELECTRICAL CHARACTERISTICS (over recommended operating conditions)

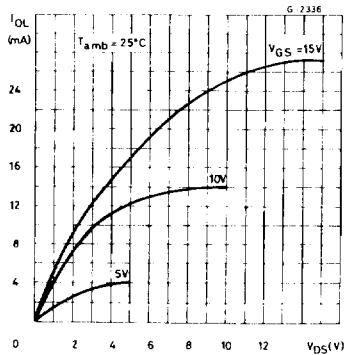
Symbol	Parameter		Test Conditions				Value						Unit	
			V _I (V)	V _O (V)	I _O (μ A)	V _{DD} (V)	T _{Low} *		25°C			T _{High} *		
							Min.	Max.	Min.	Typ.	Max.	Min.		Max.
I _L	Quiescent Current	HCC Types	0/5			5		5		0.04	5		150	μ A
			0/10			10		10		0.04	10		300	
			0/15			15		20		0.04	20		600	
		HCF Types	0/20			20		100		0.08	100		3000	
			0/5			5		20		0.04	20		150	
			0/10			10		40		0.04	40		300	
			0/15			15		80		0.04	80		600	
V _{OH}	Output High Voltage	0/5		< 1	5	4.95		4.95			4.95		V	
		0/10		< 1	10	9.95		9.95			9.95			
		0/15		< 1	15	14.95		14.95			14.95			
V _{OL}	Output Low Voltage	5/0		< 1	5		0.05			0.05		0.05	V	
		10/0		< 1	10		0.05			0.05		0.05		
		15/0		< 1	15		0.05			0.05		0.05		
V _{IH}	Input High Voltage		0.5/4.5	< 1	5	3.5		3.5			3.5		V	
			1/9	< 1	10	7		7			7			
			1.5/13.5	< 1	15	11		11			11			
V _{IL}	Input Low Voltage		4.5/0.5	< 1	5		1.5			1.5		1.5	V	
			9/1	< 1	10		3			3		3		
			13.5/1.5	< 1	15		4			4		4		
I _{OH}	Output Drive Current	HCC Types	0/5	2.5		5	-2		-1.6	-3.2		-1.15	mA	
			0/5	4.6		5	-0.64		-0.51	-1		-0.36		
			0/10	9.5		10	-1.6		-1.3	-2.6		-0.9		
		HCF Types	0/15	13.5		15	-4.2		-3.4	-6.8		-2.4		
			0/5	2.5		5	-1.53		-1.36	-3.2		-1.1		
			0/5	4.6		5	-0.52		-0.44	-1		-0.36		
			0/10	9.5		10	-1.3		-1.1	-2.6		-0.9		
0/15	13.5		15	-3.6		-3.0	-6.8		-2.4					
I _{OL}	Output Sink Current	HCC Types	0/5	0.4		5	0.64		0.51	1		0.36	mA	
			0/10	0.5		10	1.6		1.3	2.6		0.9		
			0/15	1.5		15	4.2		3.4	6.8		2.4		
		HCF Types	0/5	0.4		5	0.52		0.44	1		0.36		
			0/10	0.5		10	1.3		1.1	2.6		0.9		
			0/15	1.5		15	3.6		3.0	6.8		2.4		
I _{IH} , I _{IL}	Input Leakage Current	HCC Types	0/18	Any Input		18		\pm 0.1		\pm 10 ⁻⁵	\pm 0.1		\pm 1	μ A
		HCF Types	0/15			15		\pm 0.3		\pm 10 ⁻⁵	\pm 0.3		\pm 1	
I _O	3-state Output	HCC Types	0/18			18		\pm 0.4		\pm 10 ⁻⁴	\pm 0.4		\pm 12	μ A
		HCF Types	0/15			15		\pm 1.0		\pm 10 ⁻⁴	\pm 1.0		\pm 7.5	
C _I	Input Capacitance			Any Input						5	7.5		pF	

* T_{Low} = -55°C for HCC device; -40°C for HCF device.* T_{High} = +125°C for HCC device; +85°C for HCF device.The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD} = 5V, 2V min. with V_{DD} = 10V, 2.5 V min. with V_{DD} = 15V.

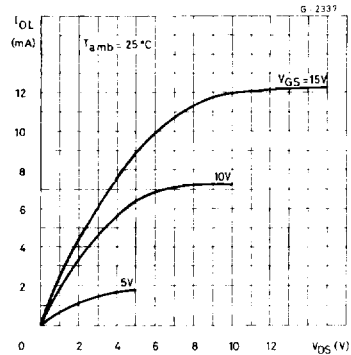
DYNAMIC ELECTRICAL CHARACTERISTICS(T_{amb} = 25°C, input t_r, t_f = 20ns, C_L = 50pF, R_L = 200kΩ, unless otherwise specified)

Symbol	Parameter	Test Conditions		Value			Unit	
		V _{DD} (V)	Min.	Typ.	Max.			
t _{THL} , t _{TLH}	Transition Time	5		100	200		ns	
		10		50	100			
		15		40	80			
t _{w(R)}	Reset Pulse Width	5	200	100			ns	
		10	140	70				
		15	100	50				
t _{w(st)}	Strobe Pulse Width	5	140	70			ns	
		10	80	40				
		15	70	35				
t _{setup}	Setup Time	5	50	25			ns	
		10	30	15				
		15	20	10				
t _H	Hold Time	5	0	0			ns	
		10	0	0				
		15	0	0				
t _{PHL} , t _{PLH}	Propagation Delay Time:	Strobe to Data Out	5		130	260		ns
			10		70	140		
			15		50	100		
		Data in to Data Out	5		105	210		ns
			10		60	120		
			15		45	90		
		Reset to Data Out	5		90	180		ns
			10		50	100		
			15		40	80		
t _{PHZ}	3-State Propagation Delay Time: Output High to High impedance	5		90	180		ns	
		10		50	100			
		15		35	70			
t _{PZH}	High Impedance to Output High	5		90	180		ns	
		10		50	100			
		15		35	70			
t _{PLZ}	Output Low to High Impedance	5		90	180		ns	
		10		50	100			
		15		35	70			
t _{PZL}	High Impedance to Output Low	5		90	180		ns	
		10		50	100			
		15		35	70			

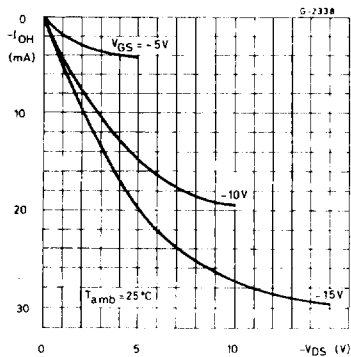
Typical Output Low (sink) Current Characteristics.



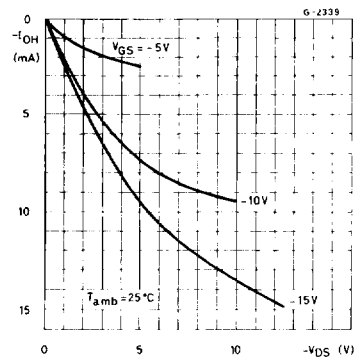
Minimum Output Low (sink) Current Characteristics.



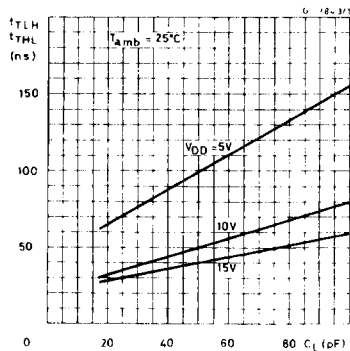
Typical Output High (source) Current Characteristics.



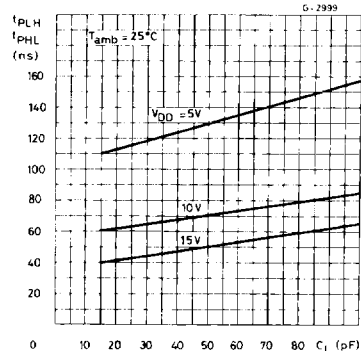
Minimum Output High (source) Current Characteristics.



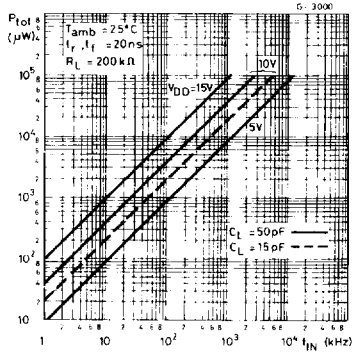
Typical Transition Time vs. Load Capacitance.



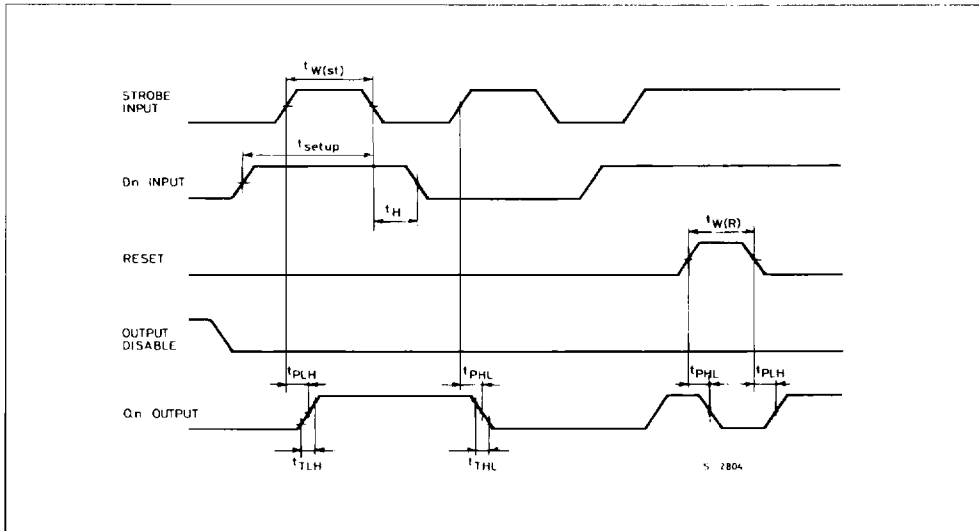
Typical Propagation Delay Time vs. Load Capacitance (strobe to dataout).



Typical Power Dissipation vs. Frequency .

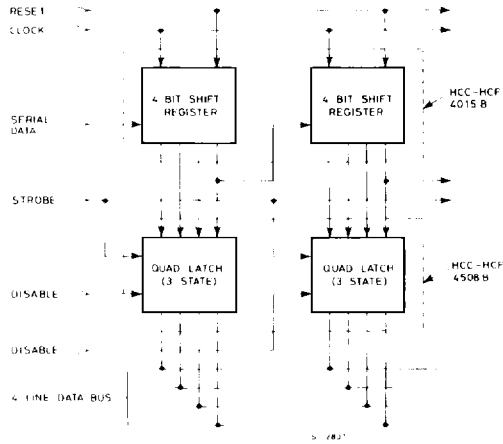


TEST WAVEFORM

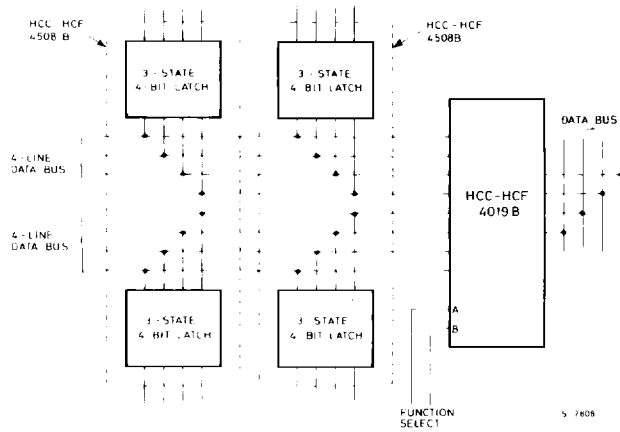


TYPICAL APPLICATIONS

A) Figure 15 : Bus register.



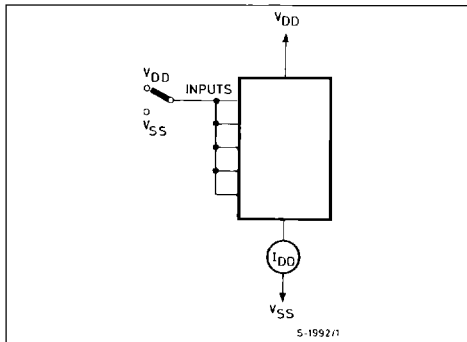
B) Figure 16 : Dual multiplexed bus register with function select.



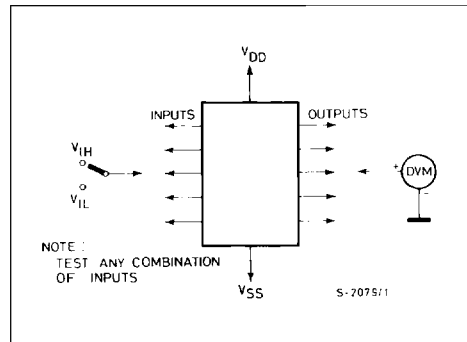
A	B	Function
0	0	Inhibit (all 0)
1	0	Select A Bus
0	1	Select B Bus
1	1	A + B

TEST CIRCUITS

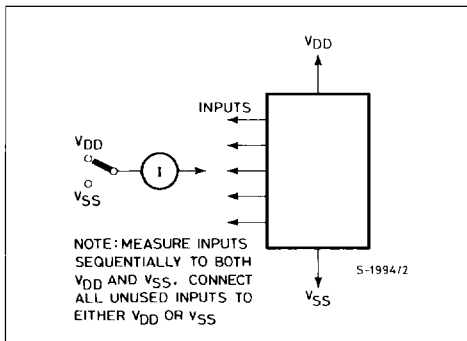
Quiescent Device Current Test Circuit.



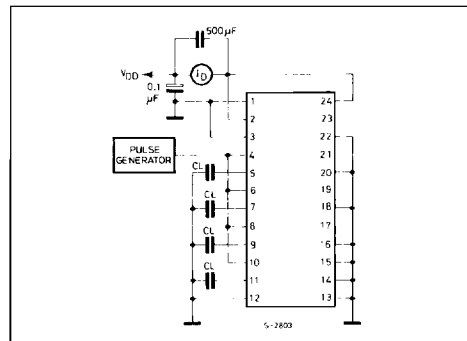
Input Voltage Test Circuit.



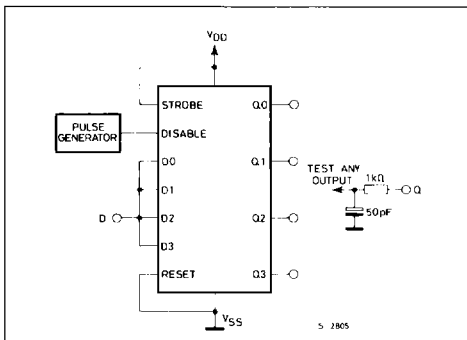
Input Current Test Circuit.



Power Dissipation Test Circuit.



Output Disable.



Waveform.

